



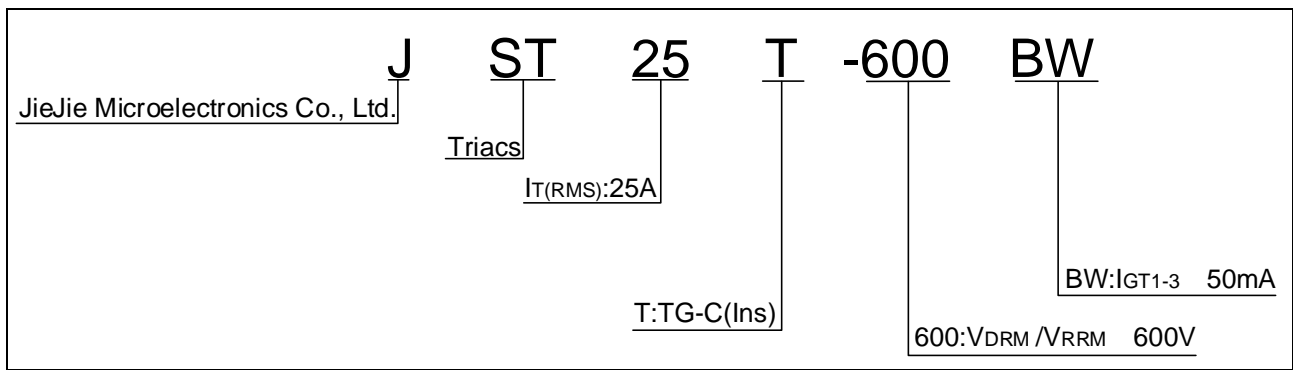
JST25T

Peak pulse voltage ($T_c = 25^\circ\text{C}$, non-repetitive off-state, FIG. 7)	V_{pp}	2.5	kV
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ELECTRICAL CHARACTERISTICS

56B>C /P150.00nCID 6 >>B21C /TT2 1 362 1 Tf

ORDERING INFORMATION



MARKING

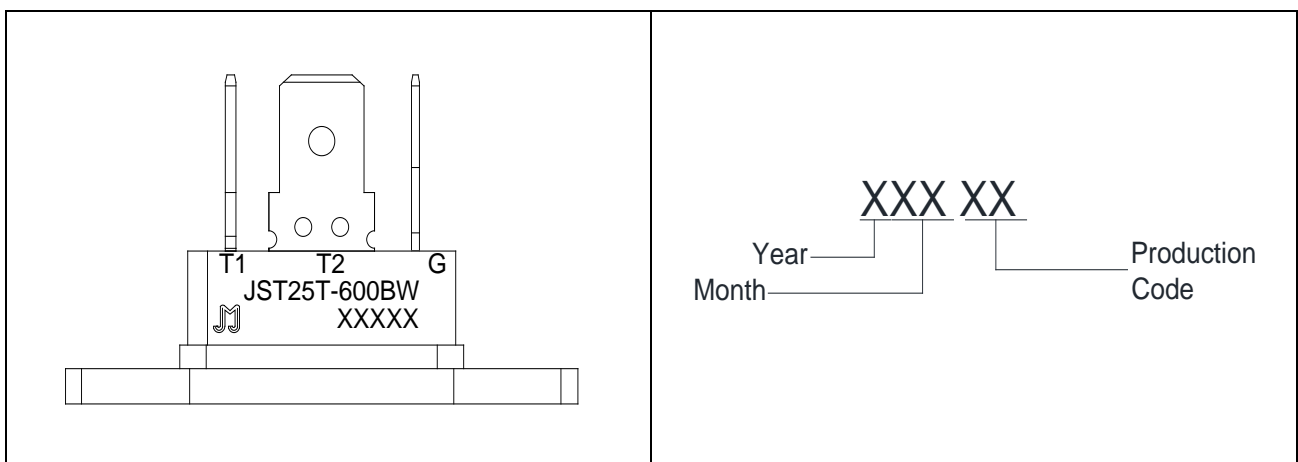


FIG.1: Maximum power dissipation versus RMS on-state current

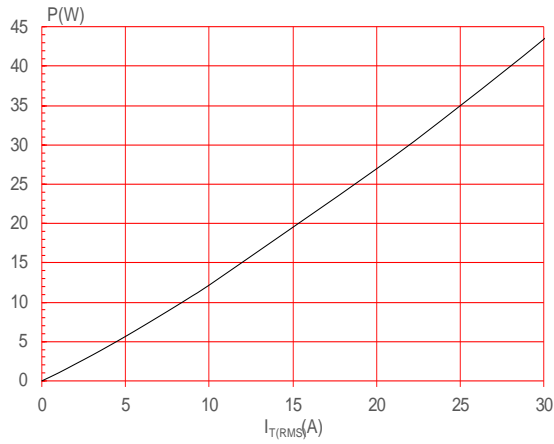


FIG.2: RMS on-state current versus case temperature

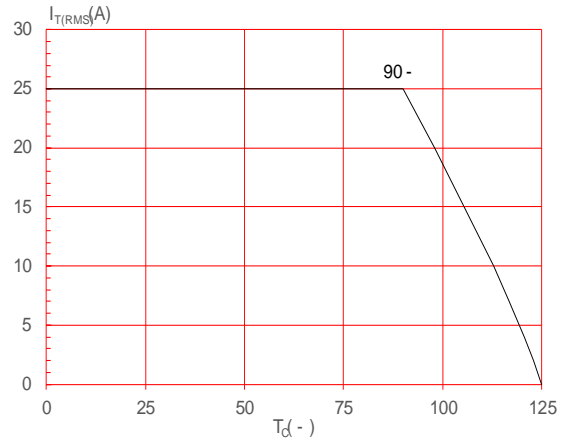


FIG.3: Surge peak on-state current versus number of cycles

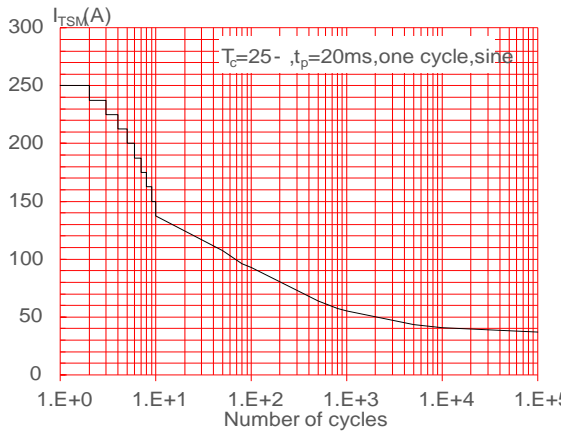


FIG.4: On-state characteristics

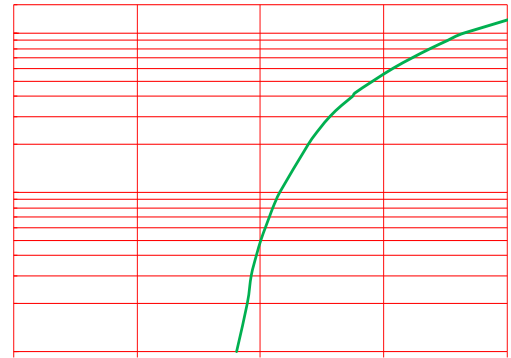
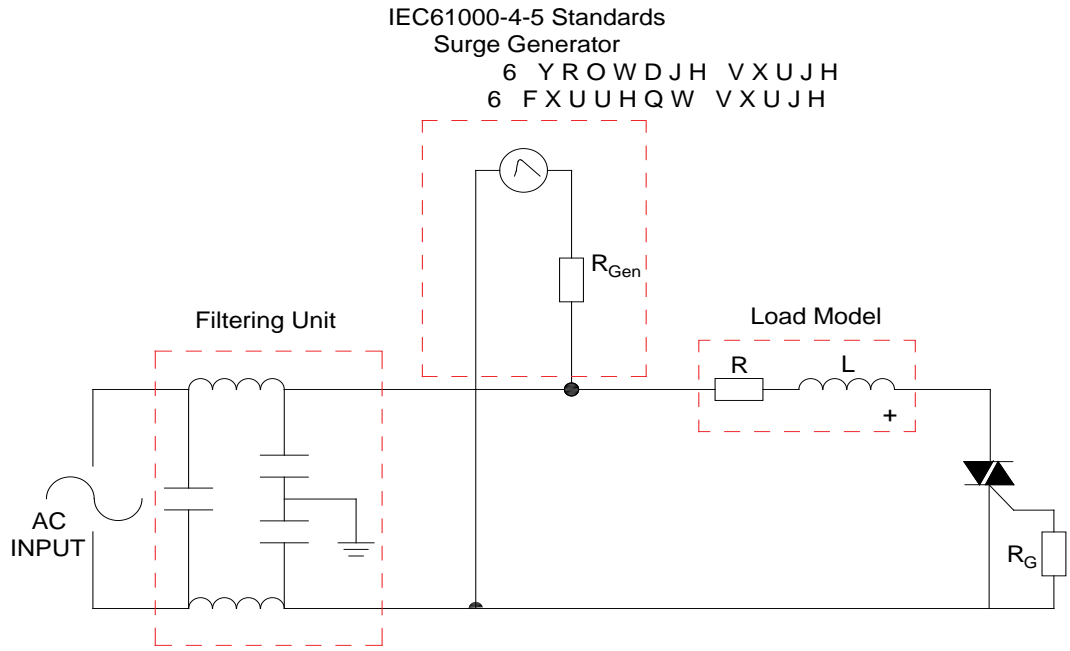


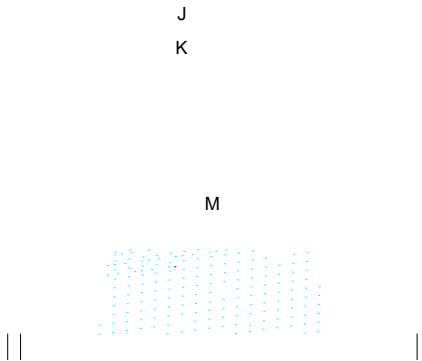
FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}(V)$	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		H- I- J			
JST25T-600BW	600	50	TG-C(Ins)	10	Tube .48 96.6 674.04

PACKAGE MECHANICAL DATA



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